



SI7923DN-T1-E3

Fabricant Numéro d'article:	SI7923DN-T1-E3
Fabricant / marque	Electro-Films (EFI) / Vishay
Partie de la description:	MOSFET 2P-CH 30V 4.3A 1212-8
Feuilles de données:	SI7923DN-T1-E3.pdf
État sans plomb / État RoHS:	 Sans plomb / conforme à la directive RoHS
Etat du stock:	Nouvel original, stock 3000 disponible.
Bateau de:	Hong Kong
Manière d'expédition:	DHL/Fedex/TNT/UPS

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SI7923DN-T1-E3 100% Nouveaux originaux 3000 en stock, Trouver SI7923DN-T1-E3 Prix, Stock, Fiche technique chez IC Components Ltd en ligne, achetez SI7923DN-T1-E3 Electro-Films (EFI) / Vishay avec garantie. 100% de garantie de confiance. RFQ SI7923DN-T1-E3: Info@IC-Components.com



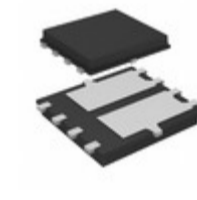
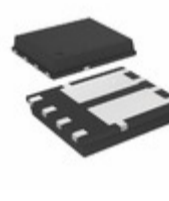
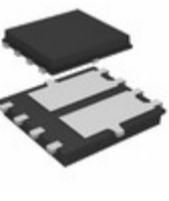
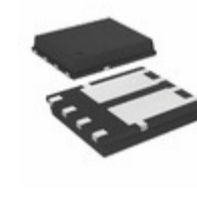


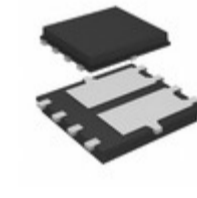

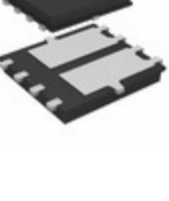

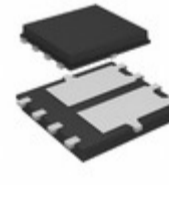
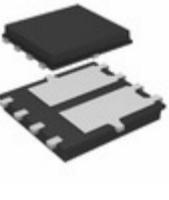
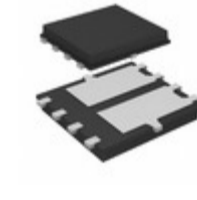


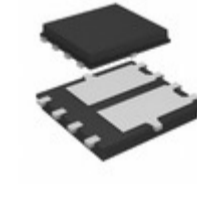
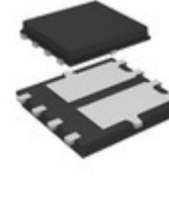
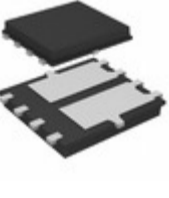

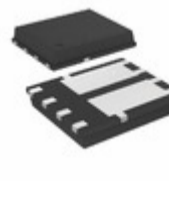

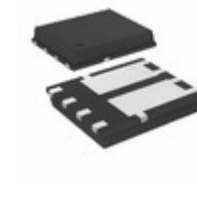
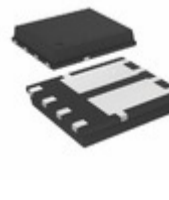



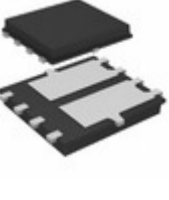
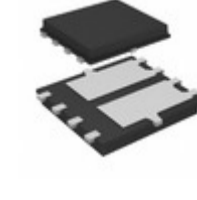
Les spécifications de SI7923DN-T1-E3

Numéro d'article	SI7923DN-T1-E3	Fabricant / marque	Electro-Films (EFI) / Vishay
Séries	TrenchFET®	Niveau de sensibilité à l'humidité (MSL)	1 (Unlimited)
Numéro de pièce de base	SI7923	Package / Boîte	PowerPAK® 1212-8 Dual
Emballage	Cut Tape (CT)	Type de montage	Surface Mount
Package composant fournisseur	PowerPAK® 1212-8 Dual	Température de fonctionnement	-55°C ~ 150°C (TJ)
Description détaillée	Mosfet Array 2 P-Channel (Dual) 30V 4.3A 1.3W Surface Mount PowerPAK® 1212-8 Dual	Puissance - Max	1.3W
type de FET	2 P-Channel (Dual)	Fonction FET	Logic Level Gate
Tension drain-source (Vdss)	30V	Courant - Drainage continu (Id) à 25 ° C	4.3A
Rds On (Max) @ Id, Vgs	47 mOhm @ 6.4A, 10V	Vgs (th) (Max) @ Id	3V @ 250µA
Charge de la porte (Qg) (Max) @ Vgs	21nC @ 10V	Capacité d'entrée (Ciss) (Max) @ Vds	-
Autres noms	SI7923DN-T1-E3CT	Quantité en stock	3000 pcs Stock
Catégorie	Produits semi-conducteurs discrets > Transistors - FET, MOSFET - tableaux	La description	MOSFET 2P-CH 30V 4.3A 1212-8
État sans plomb / État RoHS	Sans plomb / conforme à la directive RoHS		

Mots-clés associés à SI7923DN-T1-E3

Electro-Films (EFI) / Vishay SI7923DN-T1-E3	Partie SI7923DN-T1-E3	Prix SI7923DN-T1-E3	Distributeur SI7923DN-T1-E3
SI7923DN-T1-E3 technique	Action SI7923DN-T1-E3	SI7923DN-T1-E3 Inventaire	SI7923DN-T1-E3 Fournisseur
Commande en ligne SI7923DN-T1-E3	SI7923DN-T1-E3 Enquête	Image SI7923DN-T1-E3	SI7923DN-T1-E3 Image
SI7923DN-T1-E3 pdf	Fiche technique SI7923DN-T1-E3	Fiche technique SI7923DN-T1-E3	SI7923DN-T1-E3 pdf datasheet
Téléchargez la fiche technique SI7923DN-T1-E3	Electro-Films (EFI) / Vishay Fabricant	Electro-Films (EFI) / Vishay SI7923DN-T1-E3	Electro-Films (EFI) / Vishay SI7923DN-T1-E3
Vishay Electro-Films SI7923DN-T1-E3	Phoenix Passive Components / Vishay SI7923DN-T1-E3		

Vous pouvez également être intéressé par:

 SI7940DP La description: SI7940DP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 1100 disponible. Citation: RFQ	 SI7941DP La description: SI7941DP VISHAY QFN Fabricants: Vishay Precision Group En stock: Nouvel original, stock 100 disponible. Citation: RFQ	 SI7922DN-T1-E3 La description: MOSFET 2N-CH 100V 1.8A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 3000 disponible. Citation: RFQ
 SI7938DP-T1-GE3 La description: MOSFET 2N-CH 40V 60A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 700 disponible. Citation: RFQ	 SI7922DN-T1-GE3 La description: MOSFET 2N-CH 100V 1.8A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 25500 disponible. Citation: RFQ	 SI7942DP-T1-E3 La description: MOSFET 2N-CH 100V 3.8A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 2300 disponible. Citation: RFQ
 SI7904DN-T1 La description: SI7904DN-T1 VISHAY QFN Fabricants: Vishay Precision Group En stock: Nouvel original, stock 5800 disponible. Citation: RFQ	 SI7911DN-T1-GE3 QFN8 La description: SI7911DN-T1-GE3 QFN8 VISHAY QFN8 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 3000 disponible. Citation: RFQ	 SI7909DN-T1-GE3 La description: MOSFET 2P-CH 12V 5.3A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 6000 disponible. Citation: RFQ
 SI7945DP La description: SI7945DP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 200 disponible. Citation: RFQ	 SI7909DN-T1-E3 La description: MOSFET 2P-CH 12V 5.3A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 3000 disponible. Citation: RFQ	 SI7913DN-T1-GE3 La description: MOSFET 2P-CH 20V 5A PPAK 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 1100 disponible. Citation: RFQ
 SI7913DN-T1-E3 La description: MOSFET 2P-CH 20V 5A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 3000 disponible. Citation: RFQ	 SI7911DN-T1-GE3 La description: MOSFET 2P-CH 20V 4.2A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 25500 disponible. Citation: RFQ	 SI7923DN-T1-GE3 La description: MOSFET 2P-CH 30V 4.3A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 3000 disponible. Citation: RFQ
 SI7941DP-T1-E3 La description: SI7941DP-T1-E3 VISHAY QFN-8 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 4000 disponible. Citation: RFQ	 SI7911DN La description: SI7911DN VISHAY 10 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 3000 disponible. Citation: RFQ	 SI7905DN-T1-GE3 La description: MOSFET 2P-CH 40V 6A PPAK 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 15900 disponible. Citation: RFQ
 SI7904DN-T1-GE3 La description: MOSFET 2N-CH 20V 5.3A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 6000 disponible. Citation: RFQ	 SI7904DN-T1-E3 La description: MOSFET 2N-CH 20V 5.3A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 117000 disponible. Citation: RFQ	 SI7923DN-T1-e3ct-nd La description: SI7923DN-T1-e3ct-nd VISHAY QFN8 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 100 disponible. Citation: RFQ
 SI7942DP-T1-GE3 La description: MOSFET 2N-CH 100V 3.8A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 1400 disponible. Citation: RFQ	 SI7942DP La description: SI7942DP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 2000 disponible. Citation: RFQ	 SI7945DP-T1-E3 La description: MOSFET 2P-CH 30V 7A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 15900 disponible. Citation: RFQ
 SI7940DP-T1-E3 La description: MOSFET 2N-CH 12V 7.6A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 1400 disponible. Citation: RFQ	 SI7941DP-T1-GE3 La description: SI7941DP-T1-GE3 Vishay PPAKSO-8 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 1300 disponible. Citation: RFQ	 SI7925DN La description: SI7925DN SI QFN1212-8 Fabricants: SI En stock: Nouvel original, stock 100 disponible. Citation: RFQ
 SI7941DP-T1 La description: SI7941DP-T1 VISHAY QFN8 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 300 disponible. Citation: RFQ	 SI7905DN-T1-E3 La description: MOSFET 2P-CH 40V 6A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 100 disponible. Citation: RFQ	 SI7911DN-T1-E3 La description: MOSFET 2P-CH 20V 4.2A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 33000 disponible. Citation: RFQ


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